SCES026H-JULY 1995-REVISED AUGUST 2004

FEATURES

- Member of the Texas Instruments Widebus™
 Family
- EPIC[™] (Enhanced-Performance Implanted CMOS) Submicron Process
- UBT[™] (Universal Bus Transceiver) Combines
 D-Type Latches and D-Type Flip-Flops for
 Operation in Transparent, Latched, Clocked,
 or Clock-Enabled Modes
- B-Port Outputs Have Equivalent 26- Ω Series Resistors, So No External Resistors Are Required
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

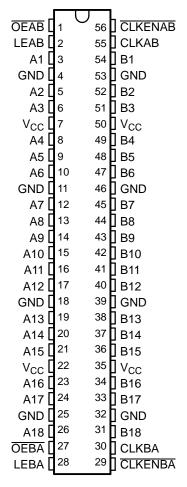
NOTE: For tape-and-reel order entry, the DGGR package is abbreviated to GR.

DESCRIPTION

This 18-bit universal bus transceiver is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74ALVCH162601 combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, clocked, and clock-enabled modes.

DGG OR DL PACKAGE (TOP VIEW)



Data flow in each direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. The clock can be controlled by the clock-enable (CLKENAB and CLKENBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is high. When LEAB is low, the A data is latched if CLKAB is held at a high or low logic level. If LEAB is low, the A data is stored in the latch/flip-flop on the low-to-high transition of CLKAB. When OEAB is low, the outputs are active. When OEAB is high, the outputs are in the high-impedance state.

Data flow for B to A is similar to that of A to B, but uses OEBA, LEBA, CLKBA, and CLKENBA.

The B-port outputs include equivalent $26-\Omega$ series resistors to reduce overshoot and undershoot.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH162601 is characterized for operation from -40°C to 85°C.

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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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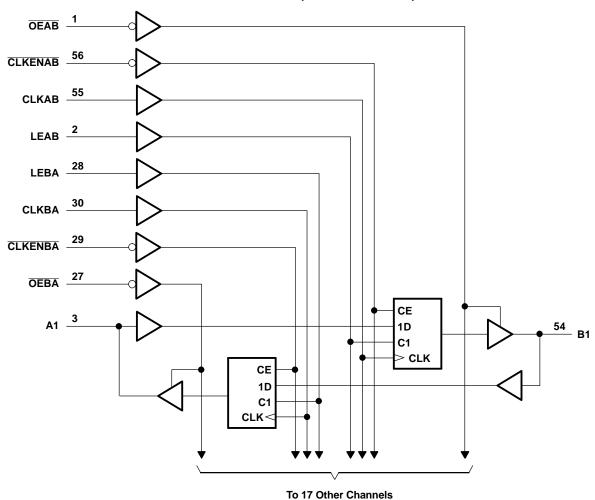


FUNCTION TABLE(1)

		INPUTS			OUTPUT
CLKENAB	OEAB	LEAB	CLKAB	Α	В
X	Н	Χ	Χ	Χ	Z
X	L	Н	Χ	L	L
X	L	Н	Χ	Н	Н
Н	L	L	Χ	X	B ₀ ⁽²⁾
н	L	L	Χ	X	B ₀ ⁽²⁾
L	L	L	\uparrow	L	L
L	L	L	\uparrow	Н	Н
L	L	L	L or H	Х	B ₀ ⁽²⁾

- (1) A-to-B data flow is shown: B-to-A flow is similar, but uses $\overline{\text{OEBA}}$, LEBA, CLKBA, and $\overline{\text{CLKENBA}}$.
- (2) Output level before the indicated steady-state input conditions were established

LOGIC DIAGRAM (POSITIVE LOGIC)





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ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

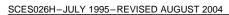
			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
\/	land to the manage	Except I/O ports ⁽²⁾	-0.5	4.6	
V _I	Input voltage range	I/O ports ⁽²⁾⁽³⁾	-0.5	V _{CC} + 0.5	V
Vo	Output voltage range ⁽²⁾⁽³⁾	·	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0	•	-50	mA
Io	Continuous output current	·		±50	mA
	Continuous current through each V _{CC} of	or GND		±100	mA
	Davidson (4)	DGG package		81	0000
θ_{JA}	Package thermal impedance (4)	DL package		74	°C/W
T _{stg}	Storage temperature range	•	-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

³⁾ This value is limited to 4.6 V maximum.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51.





RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage		1.65	3.6	V
		V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		
V_{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7		V
		V _{CC} = 2.7 V to 3.6 V	2		
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
		V _{CC} = 2.7 V to 3.6 V		0.8	
V _I	Input voltage	•	0	V _{cc}	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 1.65 V		-4	
	LP at level autout aumout (A a au)	V _{CC} = 2.3 V		-12	
	High-level output current (A port)	V _{CC} = 2.7 V		-12	
		V _{CC} = 3 V		-24	4
ОН		V _{CC} = 1.65 V		-2	mA
	Lligh level output ourrent (D.nort)	V _{CC} = 2.3 V		-6	
	High-level output current (B port)	V _{CC} = 2.7 V		-8	
		V _{CC} = 3 V		-12	
		V _{CC} = 1.65 V		4	
	Low-level output current (A port)	V _{CC} = 2.3 V		12	
	Low-level output current (A port)	$V_{CC} = 2.7 \text{ V}$		12	
		V _{CC} = 3 V		24	A
OL		V _{CC} = 1.65 V		2	mA
	Low lovel output ourrent (P. port)	$V_{CC} = 2.3 \text{ V}$		6	
	Low-level output current (B port)	V _{CC} = 2.7 V		8	
		V _{CC} = 3 V		12	
Δt/Δv	Input transition rise or fall rate			10	ns/V
T _A	Operating free-air temperature		-40	85	°C

⁽¹⁾ All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

P	ARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP(1)	MAX	UNIT
		I _{OH} = -100 μA	1.65 V to 3.6 V	V _{CC} - 0.2		
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
		I _{OH} = -6 mA	2.3 V	2		
	A port		2.3 V	1.7		
		I _{OH} = -12 mA	2.7 V	2.2		
			3 V	2.4		
		I _{OH} = -24 mA	3 V	2		.,
′он		I _{OH} = -100 μA	1.65 V to 3.6 V	V _{CC} - 0.2		V
		I _{OH} = -2 mA	1.65 V	1.2		
		I _{OH} = -4 mA	2.3 V	1.9		
	B port		2.3 V	1.7		
		$I_{OH} = -6 \text{ mA}$	3 V	2.4		
		I _{OH} = -8 mA	2.7 V	2		
		I _{OH} = -12 mA	3 V	2		
		I _{OL} = 100 μA	1.65 V to 3.6 V		0.2	
		$I_{OL} = 4 \text{ mA}$	1.65 V		0.45	
		I _{OL} = 6 mA	2.3 V		0.4	
	A port		2.3 V		0.7	
		I _{OL} = 12 mA	2.7 V		0.4	
		I _{OL} = 24 mA	3 V		0.55	
OL		$I_{OL} = 100 \mu\text{A}$	1.65 V to 3.6 V	+	0.2	V
JL		I _{OL} = 2 mA	1.65 V		0.45	-
		$I_{OL} = 4 \text{ mA}$	2.3 V		0.4	
	B port	OL	2.3 V		0.55	
	D poin	$I_{OL} = 6 \text{ mA}$	3 V		0.55	
		I _{OL} = 8 mA	2.7 V	1	0.6	
		$I_{OL} = 12 \text{ mA}$	3 V		0.8	
		$V_1 = V_{CC}$ or GND	3.6 V		±5	μΑ
		$V_1 = 0.58 \text{ V}$	0.0 v	25	-5	μΛ
		$V_1 = 0.00 \text{ V}$	1.65 V	-25		
		$V_1 = 0.7 \text{ V}$		45		
		V ₁ = 0.7 V V ₁ = 1.7 V	2.3 V	-45 -45		μΑ
hold)		V _I = 0.8 V		75		μΑ
		$V_{l} = 0.8 \text{ V}$ $V_{l} = 2 \text{ V}$	3 V	-75		
		$V_1 = 0$ to 3.6 $V^{(2)}$	3.6 V		±500	
Z ⁽³⁾		$V_0 = V_{CC}$ or GND	3.6 V		±10	μΑ
		$V_0 = V_{CC}$ or GND, $I_0 = 0$	3.6 V		40	<u>μΑ</u> μΑ
C	,	One input at V_{CC} - 0.6 V, Other inputs at V_{CC} or GND	3 V to 3.6 V		750	<u>μΑ</u> μΑ
I _{CC}	Control inputs	$V_I = V_{CC}$ or GND	3.3 V	4	730	μΑ pF
i i	A or B ports	$V_0 = V_{CC}$ or GND	3.3 V	8		рг pF

All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$. This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to

⁽³⁾ For I/O ports, the parameter I_{OZ} includes the input leakage current.

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TIMING REQUIREMENTS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

				V _{CC} =	1.8 V	V _{CC} = 1 ± 0.2	2.5 V 2 V	V _{CC} =	2.7 V	V _{CC} = ± 0.3	3.3 V 3 V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{clock}	Clock frequency				(1)		140		150		150	MHz
	Pulse duration	LE high		(1)		3.3		3.3		3.3		
l t _w	Puise duration	CLK high or low		(1)		3.3		3.3		3.3		ns
		Data before CLK1		(1)		2.3		2.4		2.1		
	Catum tima	Data before LE↓	CLK high	(1)		2		1.6		1.6		
t _{su}	Setup time	Data before LEV	CLK low	(1)		1.3		1.2		1.1		ns
		CLKEN before CL	K↑	(1)		2		2		1.7		
		Data after CLK↑		(1)		0.7		0.7		0.8		
	l lalal tima	Data after LE↓	CLK high	(1)		1.3		1.6		1.4		
t _h	Hold time	Data after LE↓	CLK low	(1)		1.7		2		1.7		ns
		CLKEN after CLK	<u> </u>	(1)		0.3		0.5		0.6		

⁽¹⁾ This information was not available at the time of publication.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V	V _{CC} = ± 0.	2.5 V 2 V	V _{CC} = 2.7 V	V _{CC} = ± 0.	3.3 V 3 V	UNIT
	(INFOT)	(001701)	MIN TYP	MIN	MAX	MIN MAX	MIN	MAX	
f _{max}			(1)	140		150	150		MHz
	Α	В	(1)	1.3	4.8	5.2	1.6	4.5	
	В	Α	(1)	1	4.3	4.6	1	4.1	
	LEAB	В	(1)	1	5.5	5.9	1.5	5.1	ns
t _{pd}	LEBA	Α	(1)	1	5	5.3	1	4.7	115
	CLKAB	В	(1)	1.5	6.1	6.3	1.6	5.5	
	CLKBA	Α	(1)	1.3	5.6	5.8	1.4	5	
t _{en}	OEAB	В	(1)	1.6	6.1	6.7	1.6	5.7	ns
t _{dis}	OEAB	В	(1)	1.8	5.7	5.3	1.8	4.8	ns
t _{en}	OEBA	Α	(1)	1.1	5.5	6.1	1.1	5.2	ns
t _{dis}	OEBA	Α	(1)	1.3	5.2	4.8	1.6	4.4	ns

⁽¹⁾ This information was not available at the time of publication.

OPERATING CHARACTERISTICS

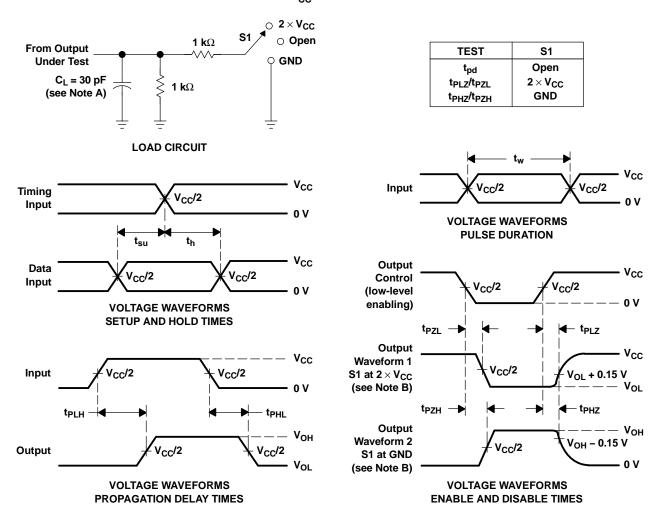
 $T_A = 25^{\circ}C$

	PARAMET	ER	TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	UNIT
	Power dissipation	Outputs enabled	C ₁ = 50 pF. f = 10 MHz	(1)	41	50	pF
C _{pd}	capacitance	Outputs disabled	$C_L = 50 \text{ pF}, f = 10 \text{ MHz}$	(1)	6	6	рг

⁽¹⁾ This information was not available at the time of publication.

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PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V}$

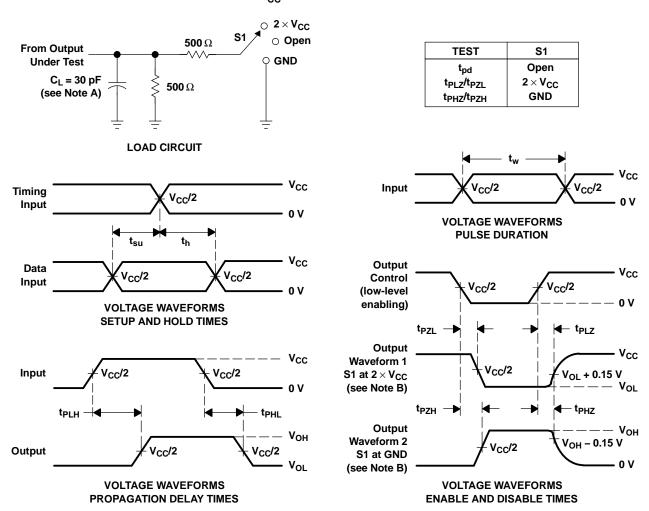


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z $_{O}$ = 50 Ω , t_{f} \leq 2 ns, t_{f} \leq 2 ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. $t_{Pl,7}$ and t_{PH7} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.5 V \pm 0.2 V



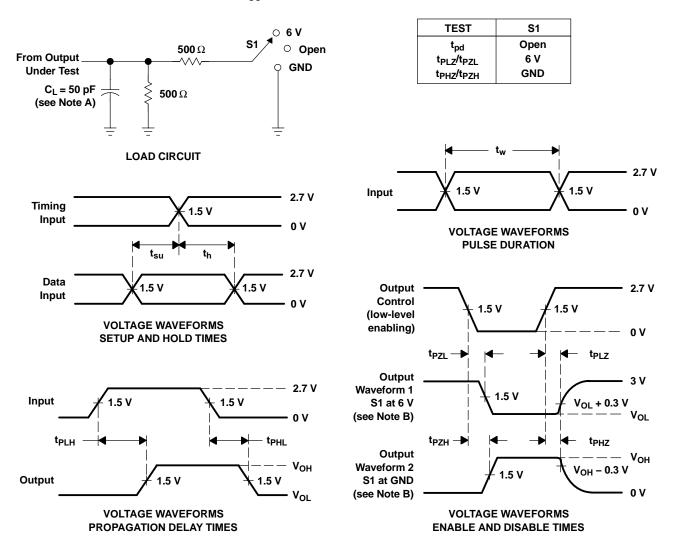
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r \leq$ 2 ns, $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.

Figure 2. Load Circuit and Voltage Waveforms

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PARAMETER MEASUREMENT INFORMATION V_{cc} = 2.7 V AND 3.3 V \pm 0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{Ω} = 50 Ω , $t_{f} \leq$ 2.5 ns, $t_{f} \leq$ 2.5 ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 3. Load Circuit and Voltage Waveforms



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74ALVCH162601DL	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162601	Samples
SN74ALVCH162601DLR	ACTIVE	SSOP	DL	56	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162601	Samples
SN74ALVCH162601GR	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162601	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

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PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

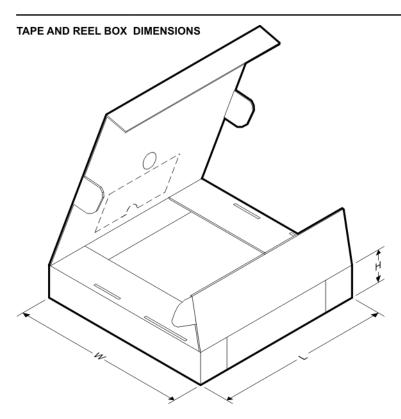
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVCH162601DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
SN74ALVCH162601GR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVCH162601DLR	SSOP	DL	56	1000	367.0	367.0	55.0
SN74ALVCH162601GR	TSSOP	DGG	56	2000	367.0	367.0	45.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74ALVCH162601DL	DL	SSOP	56	20	473.7	14.24	5110	7.87

DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.





SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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